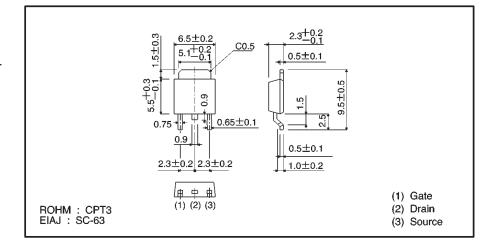
Transistors

Switching (500V, 2A) 25K2715

Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- Gate-source voltage (V_{GSS}) guaranteed to be ±30V.
- 5) Easily designed drive circuits.
- 6) Easy to use in parallel.

Structure
 Silicon N-channel
 MOSFET



External dimensions (Units: mm)

•Absolute maximum ratings (Ta = 25° C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		Vdss	500	V
Gate-source voltage		Vgss	±30	V
Drain current	Continuous	lo	2	А
	Pulsed	IDP*	6	А
Reverse drain current	Continuous	I DR	2	А
	Pulsed	IDRP*	6	А
current Pulsed Total power dissipation (Tc=25°C)		Po	20	W
Channel temperature		Tch	150	Ĉ
Storage temperature		Tstg	-55~+150	Ĉ

* Pw \leq 10 μ s, Duty cycle \leq 1%

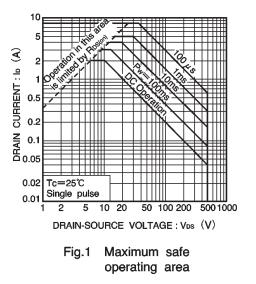
Packaging specifications

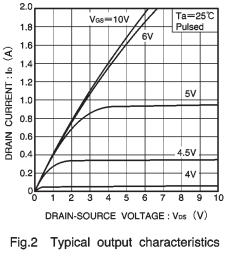
	Package	Taping
Туре	Code	TL
	Basic ordering unit (pieces)	2500
2SK2715		0

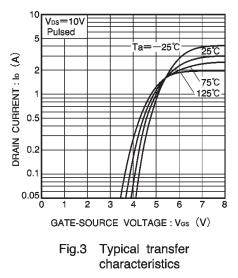
•Electrical characteristics (Ta = 25° C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Gate-source leakage	lass	—	_	±100	nA	$V_{GS}=\pm 30V, V_{DS}=0V$
Drain-source breakdown voltage	V(BR)DSS	500	_	_	V	ID=1mA, VGS=0V
Zero gate voltage drain current	loss	—	_	100	μA	V_{DS} =500V, V_{GS} =0V
Gate threshold voltage		2.0	_	4.0	V	V _{DS} =10V, I _D =1mA
Static drain-source on-state resistance	RDS(on)	_	3.0	4.0	Ω	ID=1A, VGS=10V
Forward transfer admittance	Y _{fs}	0.6	1.5	_	S	ID=1A, VDS=10V
Input capacitance	Ciss		280		pF	V _{DS} =10V
Output capacitance	Coss	—	58	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	23	_	pF	f=1MHz
Turn-on delay time	td(on)	_	10	_	ns	I□=1A, V□□≒150V
Rise time	tr		12		ns	V _{GS} =10V
Turn-off delay time	td(off)		30		ns	R∟=150Ω
Fall time	tr		63		ns	Rg=10Ω
Reverse recovery time	trr	—	410	_	ns	IDR=2A, VGS=0V
Reverse recovery charge	Qrr		1.7	_	μC	di/dt=100A/ μs

Electrical characteristic curves

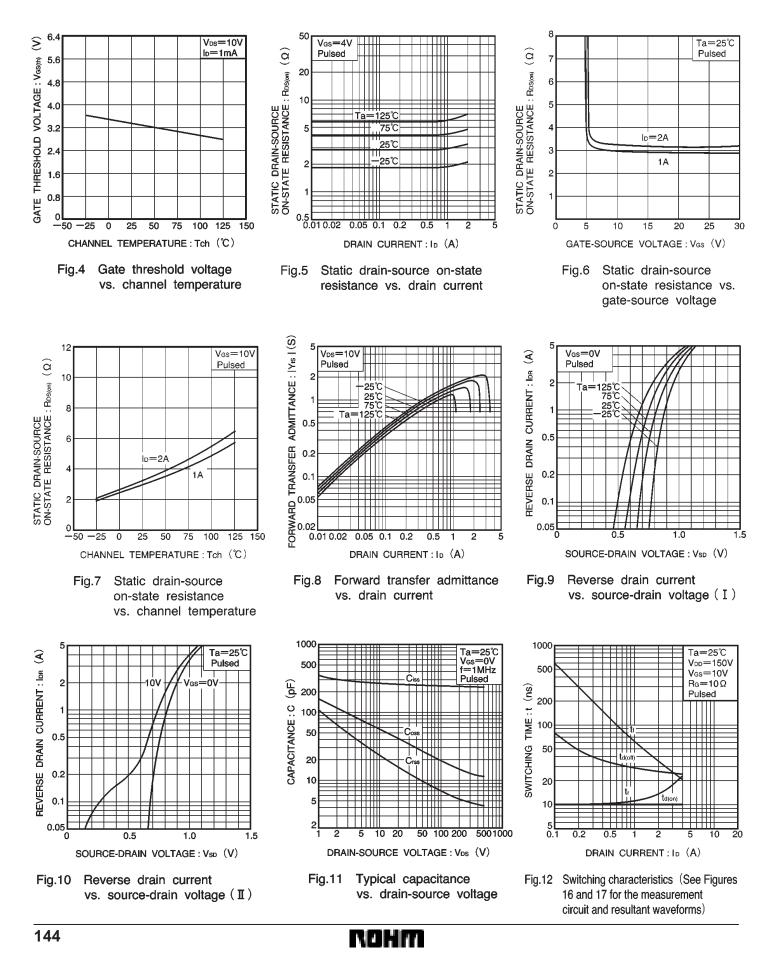




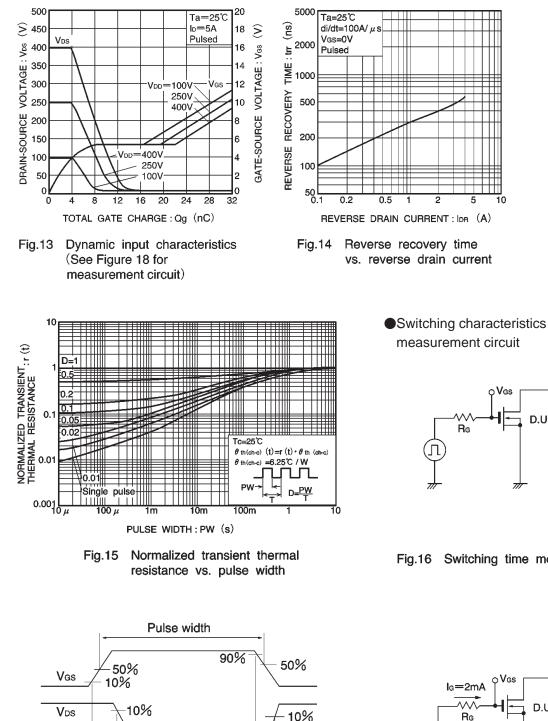


ROHM

Transistors



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90%

ROHM

tr

toff

td (off)

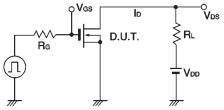


Fig.16 Switching time measurement circuit

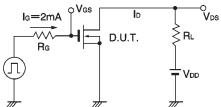


Fig.18 Gate charge measurement circuit

td(on)

tor

tr

90%

Fig.17 Switching time waveforms

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